SPICE Device Model Si7115DN



Vishay Siliconix

P-Channel 150 V (D-S) MOSFET

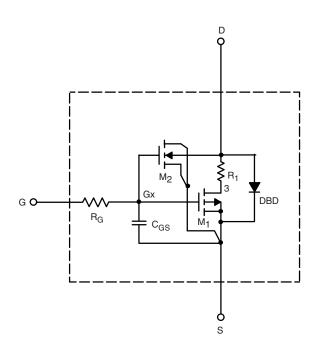
DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics



Note

 This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static	<u>.</u>				
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	2	-	V
On-State Darin Currenta	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	41	-	А
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 4 A	0.244	0.245	Ω
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -3 \text{ A}$	0.258	0.260	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 4 A	6	12	S
Diode Forward Voltage ^a	V _{SD}	I _S = - 3 A, V _{GS} = 0 V	- 0.82	- 0.80	V
Dynamic ^b		•	-	• • • •	
Input Capacitance	C _{iss}	V _{DS} = - 50 V, V _{GS} = 0 V, f = 1 MHz	1285	1190	pF
Output Capacitance	C _{oss}		65	61	
Reverse Transfer Capacitance	C _{rss}		50	42	
Total Gate Charge	Qg	$V_{DS} = -75 \text{ V}, \text{ V}_{GS} = -10 \text{ V}, \text{ I}_{D} = -3 \text{ A}$	23	27.5	nC
			16	23.2	
Gate-Source Charge	Q _{gs}	$V_{DS} = -75 \text{ V}, V_{GS} = -6 \text{ V}, I_D = -3 \text{ A}$	5.4	5.4	
Gate-Drain Charge	Q _{gd}] [8.4	8.4	

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.



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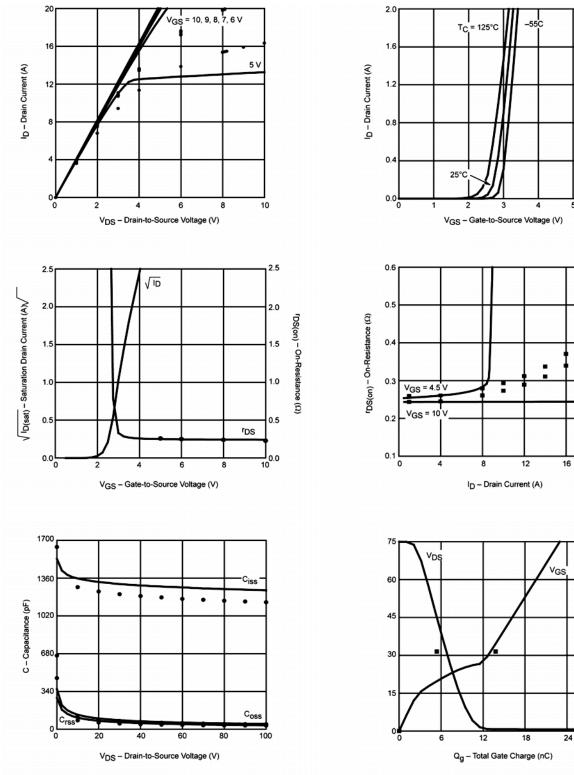
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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

• Dots and squares represent measured data.

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